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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO. 9927	
09/473,391	12/28/1999	KENNETH C. CADIEN	042390.P8136		
75	90 06/12/2003				
RAYMOND J WERNER BLAKELY SOKOLOFF TAYLOR ZAFMAN LLP 12400 WILSHIRE BOULEVARD 7TH FLOOR			EXAMINER		
			CHEN, KIN CHAN		
LOS ANGELES	S, CA 90025		ART UNIT PAPER NUMBER		
		•	1765	$\circ$	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Applicat	tion No.	<del></del>				
Office Action Summary		•	Applicant(s)				
		391 	CADIEN ET AL.				
		er	Art Unit				
		Chen .	1765				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.  - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.  - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).  - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).  Status							
1	esponsive to communication(s) filed on <u>19 May 2003</u> .						
2a)⊠ This action is <b>FINAL</b> .	b)☐ This action is	non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.  Disposition of Claims							
4)⊠ Claim(s) <u>1-8,10-12,14,24 and 25</u> is/are pending in the application.							
4a) Of the above claim(s) is/are withdrawn from consideration.							
5) Claim(s) is/are allowed.							
6)⊠ Claim(s) <u>1-8,10-12,14,24 and 25</u> is/are rejected.							
7) Claim(s) is/are objected to.							
8) Claim(s) are subject to restriction and/or election requirement.							
Application Papers							
9)☐ The specification is objected to by the Examiner.							
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
11)☐ The proposed drawing correction filed on is: a)☐ approved b)☐ disapproved by the Examiner.							
If approved, corrected drawings are required in reply to this Office action.							
12)☐ The oath or declaration is objected to by the Examiner.							
Priority under 35 U.S.C. §§ 119 and 120							
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).							
a)☐ All b)☐ Some * c)☐ None of:							
1. Certified copies of the priority documents have been received.							
2. Certified copies of the priority documents have been received in Application No							
<ul> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>							
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).							
a) The translation of the foreign language provisional application has been received.							
15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.							
Attachment(s)							
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTC 3) Information Disclosure Statement(s) (PTO-1449) Paper	9-948) er No(s) <u>21</u> .	4) Interview Summary (I 5) Notice of Informal Pa 6) Other:	PTO-413) Paper No(s) Itent Application (PTO-152)				
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#### **DETAILED ACTION**

# Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-3, 8, 11, 12, 24, and 25 are rejected under 35 U.S.C. 103(a) as being unpatentable over Aoki et al. (US 6,387,190; hereinafter "Aoki") in view of WO 99/53532 (IDS, Paper No. 21).

Aoki teaches that a dielectric layer may be formed over a substrate. The dielectric layer may have trenches therein. A barrier may be formed in the trenches and on a top surface of the dielectric layer. Metal may be deposited over the barrier. The metal (such as copper) may be polished with a slurry. Dielectric layer may comprise an oxide of silicon. The barrier is electrically conductive, such as tantalum. See col. 4, lines 18-51. Unlike the claimed invention, Aoki does not teach that the slurry includes abrasives such as brass. In a method of CMP for metal polishing, WO 99/53532 (page 5, lines 12-17) teaches that the slurry may include abrasives such as copper and compounds containing copper so as to enhance the polishing rate. Hence, it would have been obvious to one with ordinary skilled in the art to use brass in the slurry of Aoki

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because WO 99/53532 teaches that using a compound containing copper enhances the polishing rate and because brass is one of the most popular compound containing copper.

The instantly claimed invention differs from the combined prior art by specifying the slurry may include an abrasive harder than the metal and less harder than the barrier. But because the same materials are used with the same process steps, it would inherently contain the same properties and functions as claimed, the abrasive harder than the metal (such as copper) and less harder than the barrier (such as tantalum).

The combined prior art does not teach that the dielectric layer may be SiOF (fluorinated silicon oxide). It is a conventional dielectric. Hence, it would have been obvious to one skilled in the art at the time of invention to use conventional dielectric SiOF in the process of the combined prior art in order to provide their art recognized advantages and produce an expected result. See Boeck et al. (US 5,880,018) in the record as evidence.

As to claims 24 and 25, the combined prior art is not particular about the cooper interconnect structure, therefore, it would have been obvious to one with ordinary skill in the art to use it for forming a damascene structure because it is one of the most popular and well-known structure in the art of semiconductor device fabrication. Hence, it would have been obvious to one with ordinary skill in the art to modify the combined prior art by incorporating said damascene structure in order to provide their art recognized

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advantages and produce an expected result. See Avanzino et al. (US 6,140,239; col. 1) as evidence of well-known damascene structure.

As to dependent claim 25, the combined prior art does not teach that the dielectric layer may be SiOF (fluorinated silicon oxide). It is a conventional dielectric. Hence, it would have been obvious to one skilled in the art at the time of invention to use conventional dielectric SiOF in the process of the combined prior art in order to provide their art recognized advantages and produce an expected result. See Boeck et al. (US 5,880,018) in the record as evidence.

3. Claims 1, 2, 4-8, 10-12, 14 are rejected under 35 U.S.C. 103(a) as being unpatentable over Avanzino et al. (US 6,140,239; hereinafter "Avanzino") in view of WO 99/53532.

Avanzino teaches that a dielectric layer may be formed over a substrate (or forming a damascene structure). The dielectric layer may have trenches therein. A barrier may be formed in the trenches and on a top surface of the dielectric layer. Metal may be deposited over the barrier. The metal (such as copper) may be polished (chemical mechanical polishing) with a slurry. The slurry includes an abrasive which may comprise iron oxide. Dielectric layer may comprise an oxide of silicon. The barrier is electrically conductive, such as tantalum (see col. 4, lines 10-51).

Unlike the claimed invention, Avanzino does not teach an abrasive which may comprise brass. In a method of polishing metal structure in semiconductor device fabrication, WO 99/53532 teaches polishing metal structure using slurry. WO 99/53532

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(page 5, lines 12-17) teaches that the slurry may include abrasives such as copper and compounds containing copper so as to enhance the polishing rate. Hence, it would have been obvious to one with ordinary skilled in the art to use brass in the slurry of Avanzino because WO 99/53532 teaches that using a compound containing copper enhances the polishing rate and because brass is one of the most popular compound containing copper.

The instantly claimed invention differs from the combined prior art by specifying the slurry may include an abrasive harder than the metal and less harder than the barrier. But because the same materials are used with the same process steps, it would inherently contain the same properties and functions as claimed, the abrasive harder than the metal (such as copper) and less harder than the barrier (such as tantalum).

The limitations of claims 1, 2, 8, 11, and 12 have been addressed above.

As to dependent claim 4, the abrasive has a Moh's hardness between approximately 3.5 and 6. As to dependent claims 6 and 14, the slurry contains approximately 0.5% to 10% by weight of the abrasive. As to dependent claim 7, the slurry contains an oxidizer comprising  $H_2O_2$  (see col. 4, lines 10-12, 23-28, 41-51)

As to dependent claims 5 and 10, the combined prior art does not specify the pH value of slurry used in the process. However, it is conventional and obvious to dilute the slurry with weak acid or alkali to adjust pH value of slurry to between 3.5 to 7 in order to provide their art recognized advantages and produce an expected result because same is a well-known result-effective variable.

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### Response to Arguments

4. Applicant's arguments with respect to claims 1-8, 10-12, 14, 24, and 25 have been considered but are moot in view of the new ground(s) of rejection.

#### Conclusion

- 5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Boeck et al. (US 5,880,018) teach the conventional SiOF (see col. 7, lines 36). The reference was cited in Paper No. 8.
- 6. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of

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the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Kin-Chan Chen whose telephone number is (703) 305-0222. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Benjamin Utech can be reached on (703) 308-3836. The fax phone numbers for the organization where this application or proceeding is assigned are (703) 872-9310 for regular communications and (703) 872-9311 for After Final communications. Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-2934.

Kin-Chan Chen Primary Examiner Art Unit 1765

K-C C June 11, 2003